## NSN 5961-00-484-3019

Transistor - Page 1 of 2



View Online at https://aerobasegroup.com/nsn/5961-00-484-3019 **Inclosure Material:** Metal **Overall Length:** 1.252 inches **Overall Height:** 0.272 inches **Overall Width:** 0.700 inches **Mounting Facility Quantity: Internal Configuration:** Junction contact Joint Electronic Device Engineering Council/jedec/case Outline Designation: **Electrode Internally-electrically Connected To Case:** Collector **Mounting Method:** Unthreaded hole **Features Provided:** Hermetically sealed case **Semiconductor Material:** Silicon Voltage Rating In Volts Per Characteristic: 120.0 collector to base voltage/static/emitter open and 90.0 collector-to-emitter substaining voltage, resistance between base and emitter and 75.0 collector-to-emitter, substaining voltage, base open-circuited and 7.0 emitter to base voltage, static, collector open **Current Rating Per Characteristic:** Between 5.00 amperes source cutoff current and 10.00 amperes source cutoff current **Power Rating Per Characteristic:** 35.0 watts small-signal input power, common-collector preset **Maximum Operating Tempurature Per Measurement Point:** 200.0 degrees celsius junction **Special Features:** Junction pattern arrangement: npn **Test Data Document:** 00638-21459 drawing (this is the basic governing drawing, such as a contractor drawing, original equipment manufacturer drawing, etc.; excludes any specification, standard or other document that may be referenced in a basic governing drawing) **Terminal Type And Quantity:** 2 pin and 1 case Shelf Life: N/a

No

**Unit Of Measure:** 

**Demilitarization:** 

## **NSN 5961-00-484-3019** Transistor - Page 2 of 2



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